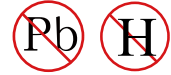




YEA SHIN TECHNOLOGY CO., LTD

SR12 THRU SR120

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

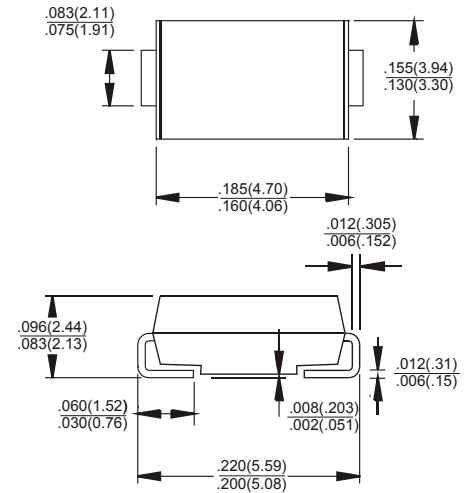


VOLTAGE- 20 to 200 Volts CURRENT- 1.0 Ampere

**FEATURES**

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Low profile package
- Built-in strain relief
- Metal to silicon rectifier. majority carrier conduction
- Low power loss,high efficiency
- High surge capacity
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C /10 seconds at terminals
- Pb free product at available : 99% Sn above meet RoHS environment substance directive request

SMB/DO-214AA Unit:inch(mm)



**MECHANICAL DATA**

- Case: JEDEC SMB/DO-214AA molded plastic
- Terminals:Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes positive end (cathode)

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.  
Resistive or inductive load.

PARAMETER	SYMBOL	SR12	SR13	SR14	SR15	SR16	SR18	SR110	SR115	SR120	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	V	
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	V	
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	80	100	150	200	V	
Maximum average forward rectified current	$I_F$	1.0									A	
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	30.0									A	
Maximum Instantaneous Forward Voltage $I_F=1A @ 25^\circ C$	$V_F$	0.50			0.70		0.85		0.87	0.90	V	
Maximum DC Reverse Current @ $T_c=25^\circ C$ at Rated DC Blocking Voltage @ $T_c=100^\circ C$	$I_R$	0.5 10					0.2 5.0				mA	
Typical Junction Capacitance(NOTE1)	$C_j$	90	70	60		50		35			pF	
Typical Thermal Resistance	$R_{\theta Ja}$ $R_{\theta Jc}$	90 60									$^\circ C/W$	
Operating Temperature Range	$T_J$	-55 to +125					-55 to +150					$^\circ C$
Storage Temperature Range	$T_{STG}$	-55 to +150										$^\circ C$

NOTES:

- 1.Measured at 1.0MHZ and applied reverse voltage of 4.0V DC
- 2.Device mounted on FR-4 substrate, 1"\*1", 2oz, single-sided, PC boards with 0.1"\*0.15" copper pad.

# DEVICE CHARACTERISTICS

## SR12 THRU SR120

FIG. 1-TYPICAL FORWARD CURRENT DERATING CURVE

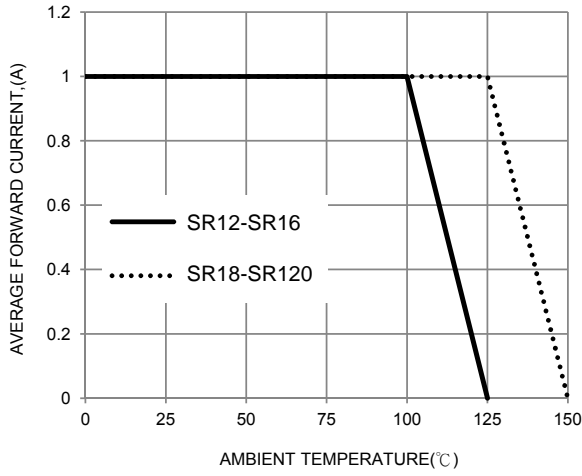


FIG. 2-TYPICAL FORWARD CHARACTERISTICS

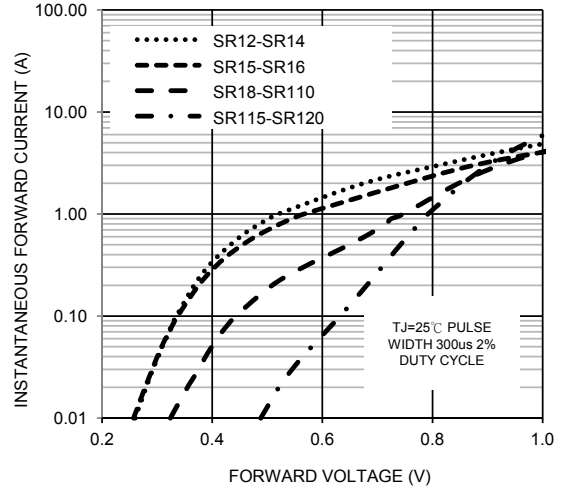


FIG. 3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

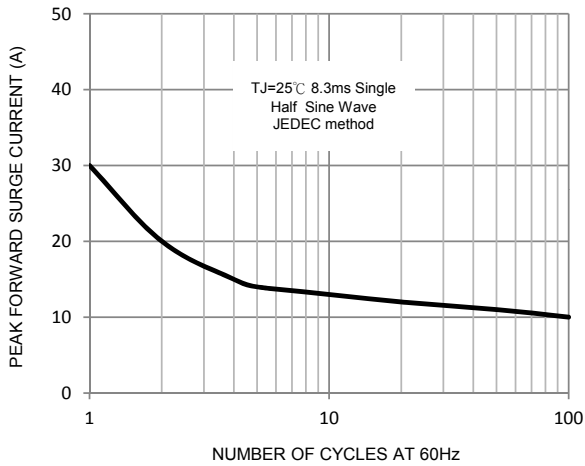


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

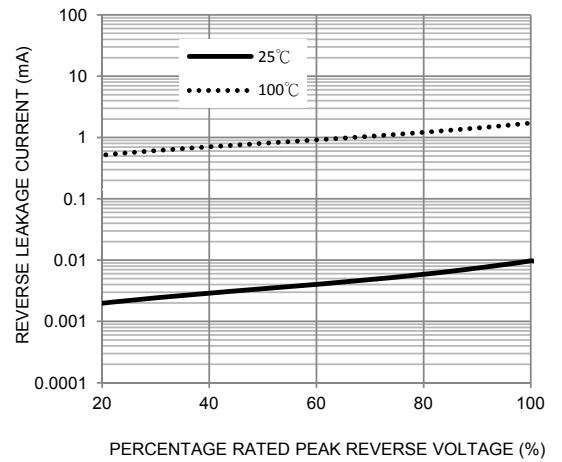


FIG. 5-TYPICAL JUNCTION CAPACITANCE

